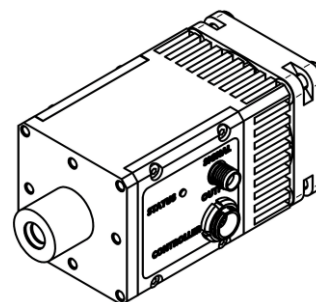


Programmable IR detection module based on HgCdTe thermoelectrically cooled optically immersed photovoltaic multi-junction detector



FEATURES

- Spectral range: 2.0 to 12.0 μm
- Frequency bandwidth: DC to 120 MHz (typ.)
- High performance and reliability
- DC offset compensation
- Integrated fan
- M4 mounting hole
- VIGO PTCC-01 TEC controller obligatory
- Compatible with optical accessories
- Versatile and flexible
- Quantity discounted price
- Fast delivery
- No minimum order quantity required

PROGRAMMABLE PARAMETERS

- Gain: in the 40 dB range
- Bandwidth: 1.5 MHz/15 MHz/120 MHz (typ.)
- Coupling: AC/DC
- Detector temperature
- Output voltage offset

APPLICATIONS

- Gas detection, monitoring and analysis: SO_2 , NH_3 , SF_6
- CBRN threats detection
- CO_2 laser measurements: power monitoring and control, beam profiling and positioning, calibration
- Free-space optical communication
- FTIR spectroscopy
- Medical bacteria identification
- Dentistry
- Glucose sensing
- Research and prototyping

DETECTION MODULE CONFIGURATION

Detection module symbol	LabM-I-10.6
Detector symbol	PVMI-4TE-10.6-1x1-TO8-wZnSeAR-36
Detector type	photovoltaic, multi-junction
Active element material	epitaxial HgCdTe heterostructure
Optical area, A_o	1 mm \times 1 mm
<u>Optical immersion</u>	hyperhemisphere
Cooling	4TE ($T_{\text{chip}} \cong 200\text{K}$)
Temperature sensor	thermistor
Acceptance angle, Φ	~ 36 deg.
Window	wZnSeAR (3 deg. wedged zinc selenide, anti-reflection coating)
Amplifier symbol	PIP
Amplifier type	programmable, transimpedance
Signal output socket	SMA
Power supply, TE cooler, thermistor and fan socket	LEMO ECG.0B.309.CLN (female)

INCLUDED ACCESSORIES

- 1 pc of SMA-BNC cable
- 1 pc of LEMO-DB9 or LEMO-DUBOX2x5 cable

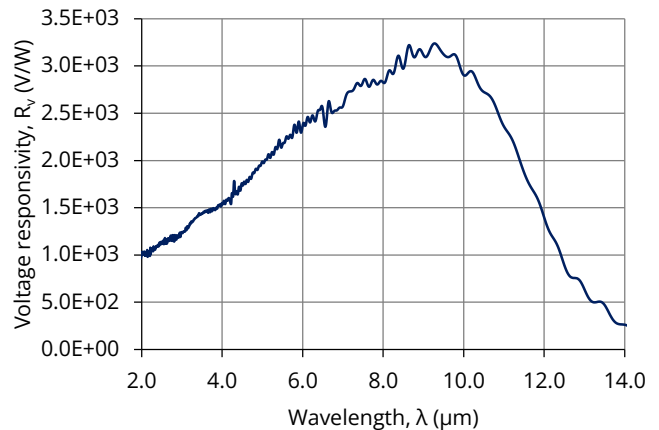
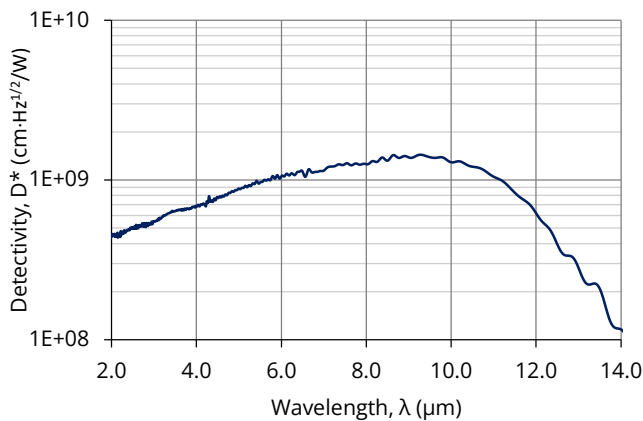
DEDICATED ACCESSORIES

- PTCC-01 TEC controller series: obligatory
- Smart Manager software: freeware
- OTA optical threaded adapter
- DRB-2 base mounting system

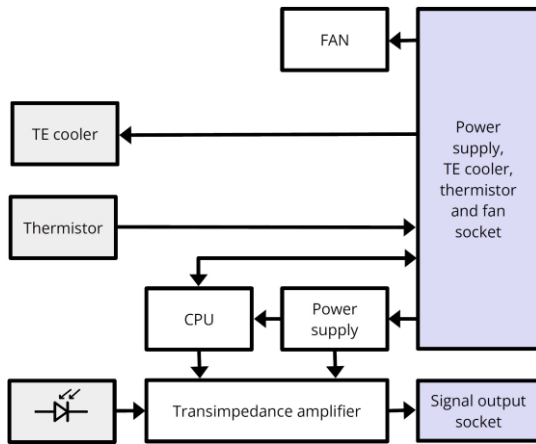
SPECIFICATION ($T_{amb} = 293\text{ K}$, $T_{chip} = 200\text{ K}$, $R_{load} = 50\ \Omega$, unless otherwise noted; default module settings)

Parameter	Test conditions, remarks	Value			Unit
		Min.	Typ.	Max.	
Active element temperature, T_{chip}		-	200	-	K
Cut-on wavelength, λ_{cut-on} (10%)	At 10% of peak responsivity	-	2.0	-	μm
Peak wavelength, λ_{peak}		-	9.0 \pm 1.0	-	μm
Specific wavelength, λ_{spec}		-	10.6	-	μm
Cut-off wavelength, $\lambda_{cut-off}$ (10%)	At 10% of peak responsivity	-	12.0	-	μm
Detectivity, D^*	At $\lambda = \lambda_{peak}$, $f = 10\text{ MHz}$	-	1.4 $\times 10^9$	-	cm \cdot Hz $^{1/2}$ /W
	At $\lambda = \lambda_{spec}$, $f = 10\text{ MHz}$	6.0 $\times 10^8$	1.2 $\times 10^9$	-	
Output noise voltage density, v_n	At $f = 10\text{ MHz}$	-	-	400	nV/Hz $^{1/2}$
Voltage responsivity, R_v	At $\lambda = \lambda_{peak}$	-	3.2 $\times 10^3$	-	V/W
	At $\lambda = \lambda_{spec}$	1.8 $\times 10^3$	2.7 $\times 10^3$	-	
Low cut-off frequency, f_{lo-DC}	DC coupling selected	-	0	-	Hz
Low cut-off frequency, f_{lo-AC}	AC coupling selected	-	10	-	Hz
High cut-off frequency, f_{hi-H}	High bandwidth selected	80	120	-	MHz
High cut-off frequency, f_{hi-M}	Mid bandwidth selected	-	15	-	MHz
High cut-off frequency, f_{hi-L}	Low bandwidth selected	-	1.5	-	MHz
Output impedance, R_{out}		-	50	-	Ω
Output voltage swing, V_{out}		-	-	± 1	V
Output voltage offset, V_{off}		-	-	± 20	mV
Power supply voltage (positive), $+V_{sup}$		-	+9	-	V
Power supply voltage (negative), $-V_{sup}$		-	-9	-	V
Power supply current consumption (positive), $+I_{sup}$		-	-	+100	mA
Power supply current consumption (negative), $-I_{sup}$		-	-	-100	mA
Fan power consumption, P_{fan}		-	-	900	mW
TEC voltage, $V_{TEC\ max}$		-	-	8.3	V
TEC current, $I_{TEC\ max}$		-	-	0.4	A
Weight		-	180	-	g

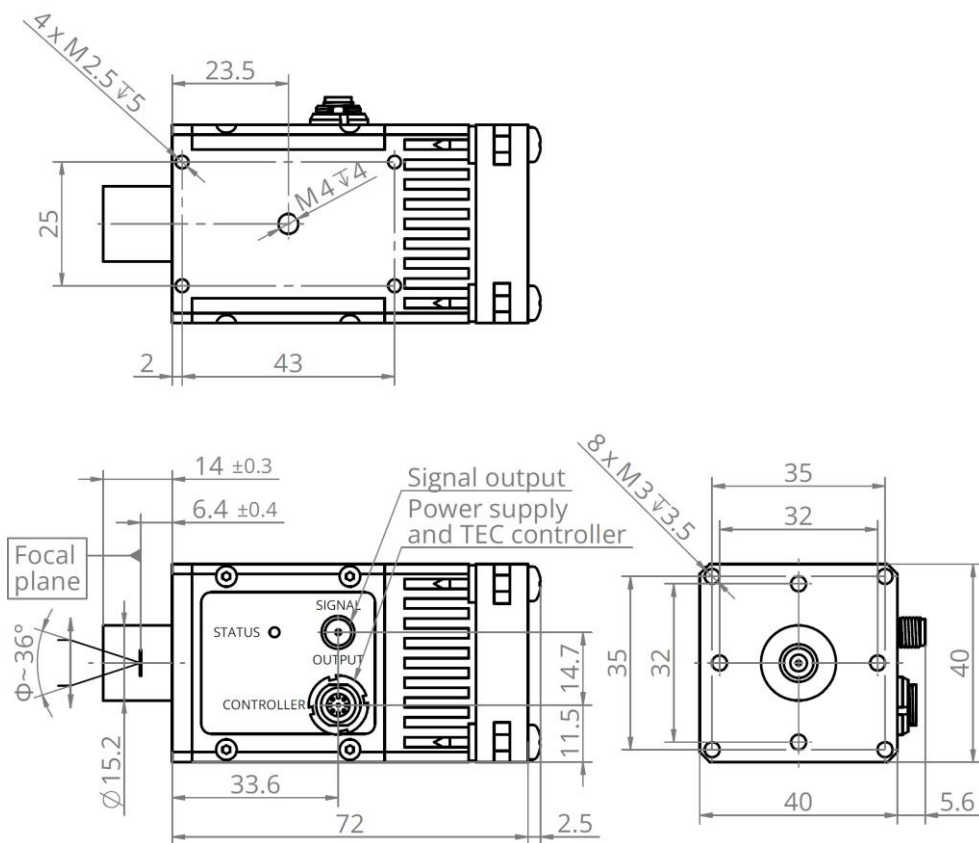
SPECTRAL RESPONSE (Typ., $T_{amb} = 293\text{ K}$, $T_{chip} = 200\text{ K}$)



SCHEMATIC DIAGRAM



MECHANICAL LAYOUT (Unit: mm)



ABSOLUTE MAXIMUM RATINGS

Parameter	Test conditions, remarks	Value	Unit
Ambient operating temperature, T_{amb}		10 to 30	°C
Storage temperature, T_{stg}		-20 to 50	°C
Humidity	No dew condensation	10 to 90	%
Maximum incident optical power density	Continuous wave (CW) or single pulses >1 μ s duration	2.5	W/cm ²
	Single pulses <1 μ s duration	10	kW/cm ²

Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. Constant or repeated exposure to absolute maximum rating conditions may affect the quality and reliability of the device